



25V NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

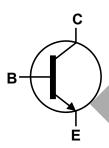
- BV_{CEO} > 25V
- I_C = 200mA Collector Current
- **Epitaxial Planar Die Construction**
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMST4126
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

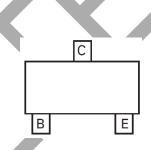
- Case: SOT323
- Case Material: Molded Plastic "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)







Device Symbol



Pin-Out Top view

Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMST4124-7-F	Standard	K1B	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K1B = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Date Code	IXCy													
Year	201	6	2017		2018	2019	2020	2021	2022	2 20	23 2	2024	2025	2026
Code	D		Е		F	G	Н		J	ŀ	(L	М	N
Mont	h	Ja	n F	eb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1		2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Collector Current	lc	200	mA

Thermal Characteristics (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	R_{\thetaJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

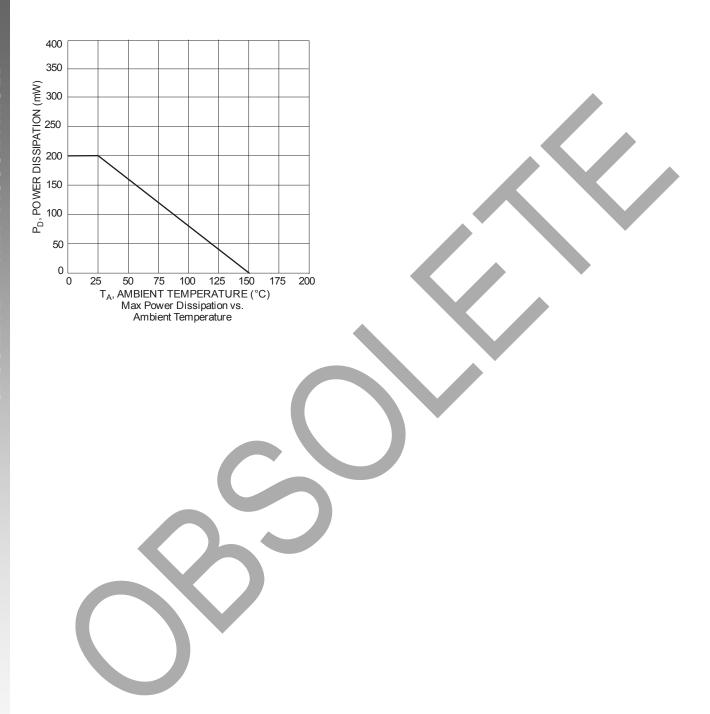
Notes:

- 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	BV _{CBO}	30	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	25	_	V	$I_C = 1mA, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	5	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}	_	50	nA	V _{CB} = 20V, I _E = 0
Base Cut-Off Current	I _{EBO}	_	50	nA	$V_{EB} = 3.0V, I_C = 0$
ON CHARACTERISTICS (Note 7)					
DC Current Gain	h	120	_		$I_C = 2mA$, $V_{CE} = 1V$
DC Current Gain	h _{FE}	60	—	_	$I_C = 50$ mA, $V_{CE} = 1$ V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.30	V	$I_C = 50$ mA, $I_B = 5$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	0.95	V	$I_C = 50$ mA, $I_B = 5$ mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_OBO	_	4	pF	$V_{CB} = 5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C_{IBO}	_	8	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$
Small Signal Current Gain	h _{FE}	120	480	_	$V_{CE} = 1.0V, I_{C} = 2mA,$ f = 1.0MHz
Current Gain-Bandwidth Product	f⊤	300	_	MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz

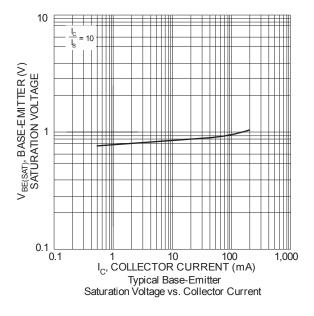
Note:

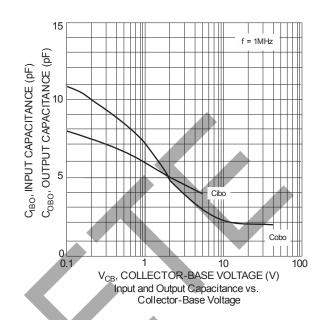
7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

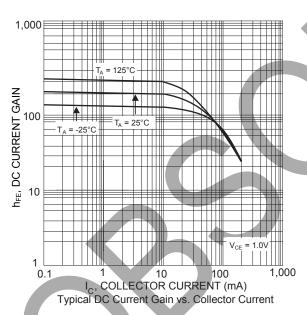


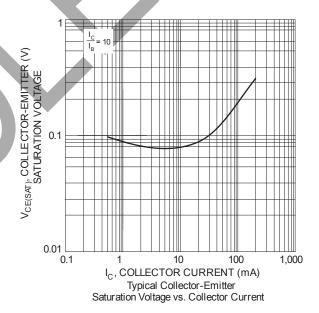


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







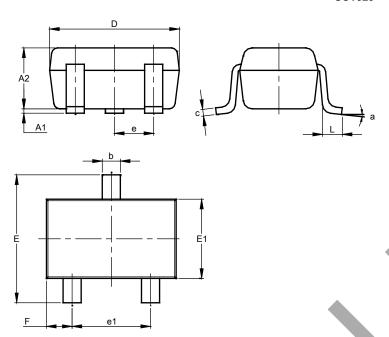




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

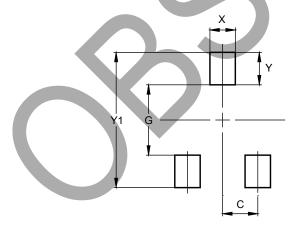


		_					
SOT323							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
E	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 B	SC				
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



Dimensions	Value
Dimensions	(in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
V1	2 500

June 2021



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